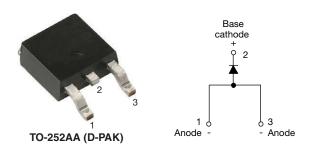
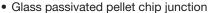


Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY							
Package	TO-252AA (D-PAK)						
I _{F(AV)}	8 A						
V _R	1000 V, 1200 V						
V _F at I _F	1.3 V						
I _{FSM}	150 A						
t _{rr}	80 ns						
T _J max.	150 °C						
Diode variation	Single die						
Snap factor	0.6						

FEATURES







• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES									
I _{F(AV)}	Sinusoidal waveform	8	A						
V _{RRM}		1000/1200	V						
I _{FSM}		150	A						
V _F	8 A, T _J = 25 °C	1.3	V						
t _{rr}	1 A, 100 A/µs	80	ns						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-8EWF10SPbF	1000	1100	4
VS-8EWF12SPbF	1200	1300	4

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	UNITS							
Maximum average forward current	I _{F(AV)}	T _C = 94 °C, 180° conduction half sine wave	8					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	s sine pulse, rated V _{RRM} applied 125					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	150					
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied 78		A ² s				
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-S				
Maximum $I^2\sqrt{t}$ for fusing $I^2\sqrt{t}$		t = 0.1 to 10 ms, no voltage reapplied	1100	A²√s				



VS-8EWF..SPbF Soft Recovery Series

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	VALUES	UNITS							
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C	1.3	V					
Forward slope resistance	r _t	T _{.1} = 150 °C	25.6	mΩ					
Threshold voltage	V _{F(TO)}	1j=150 C	0.93	V					
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	A				
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = nateu VRRM	4	- mA				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Reverse recovery time	t _{rr}	I _F at 8 A _{pk}	270	ns	I _{FM} t				
Reverse recovery current	I _{rr}	25 A/µs	4.2	А	t _a t _b				
Reverse recovery charge	Q _{rr}	T _J = 25 °C	1	μC	di / Q _{rr}				
Snap factor	S		0.6		V Im				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		50	C/VV				
Approximate weight			1	g				
Approximate weight			0.03	OZ.				
Marking device		Case style TO-252AA (D-PAK)	8EWF12S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

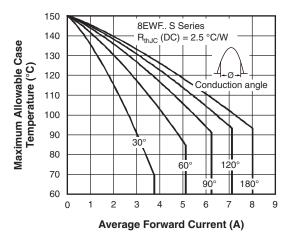


Fig. 1 - Current Rating Characteristics

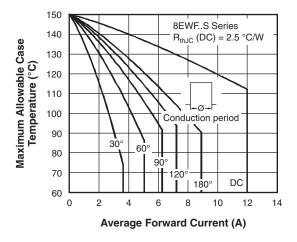


Fig. 2 - Current Rating Characteristics

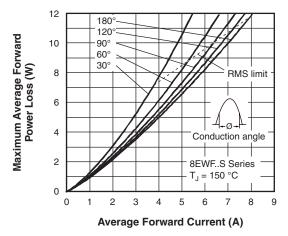


Fig. 3 - Forward Power Loss Characteristics

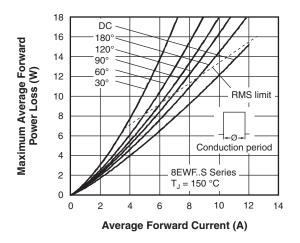


Fig. 4 - Forward Power Loss Characteristics

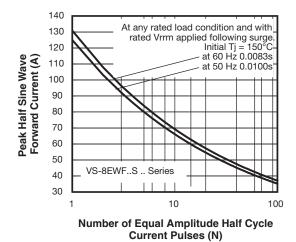


Fig. 5 - Maximum Non-Repetitive Surge Current

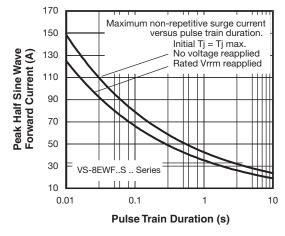


Fig. 6 - Maximum Non-Repetitive Surge Current

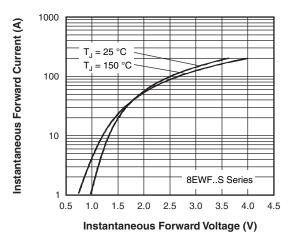


Fig. 7 - Forward Voltage Drop Characteristics

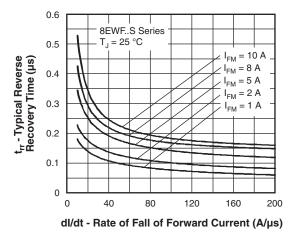


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

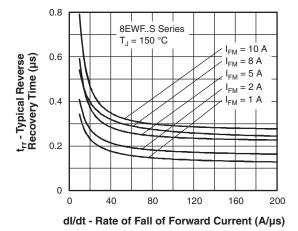


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

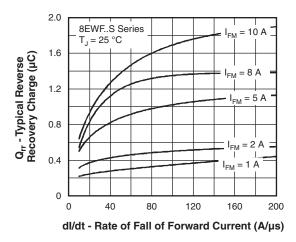


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

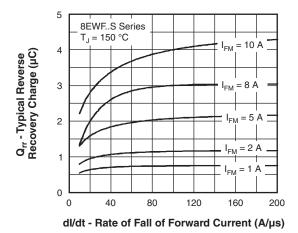


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

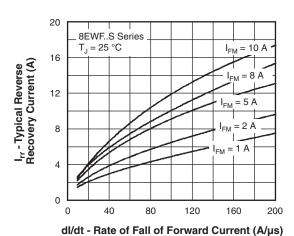


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

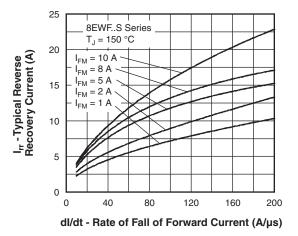


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

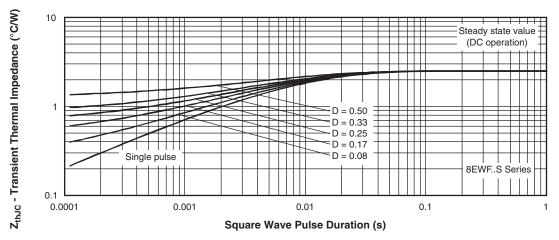


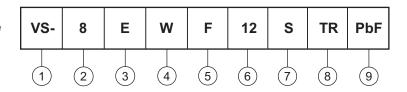
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-8EWF..SPbF Soft Recovery Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

- Voltage code x 100 = V_{RRM} -

10 = 1000 V 12 = 1200 V

7 - S = surface mountable

8 - • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - None = standard production

• PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95552						



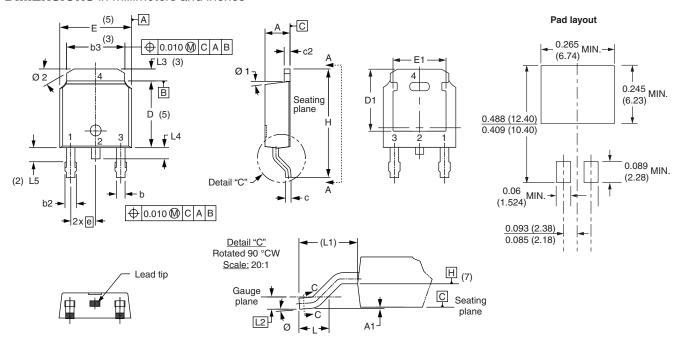
NOTES

3

2

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	3	STIVIDUL	MIN.	MAX.	MIN.	MAX.
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070
b2	0.76	1.14	0.030	0.045			L1	2.74 BSC		0.108 REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060
D1	5.21	-	0.205	1	3		Ø	0°	10°	0°	10°
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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